

# SN74LV4T125-Q1 車載用、3 ステート出力付きクワッド・バッファ・トランスレータ

## 1 特長

- 車載アプリケーション用に AEC-Q100 認定済み:
  - デバイス温度グレード 1:  $-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$
  - デバイス HBM ESD 分類レベル 2
  - デバイス CDM ESD 分類レベル C4B
- 幅広い動作範囲: 1.8V ~ 5.5V
- 単一電源電圧トランスレータ (「LVxT 拡張入力電圧」を参照):
  - 昇圧変換:
    - 1.2V から 1.8V
    - 1.5V から 2.5V
    - 1.8V から 3.3V
    - 3.3V から 5.0V
  - 降圧変換:
    - 5.0V、3.3V、2.5V から 1.8V
    - 5.0V、3.3V から 2.5V
    - 5.0V から 3.3V
- 5.5V 許容入力ピン
- 標準ピン配置をサポート
- 5V または 3.3V の  $V_{CC}$  で最大 150Mbps
- JESD 17 準拠で 250mA 超のラッチアップ性能

## 2 アプリケーション

- デジタル信号のインエーブルまたはディスエーブル
- インジケータ LED の制御
- 通信モジュールとシステム・コントローラの間の変換

## 3 概要

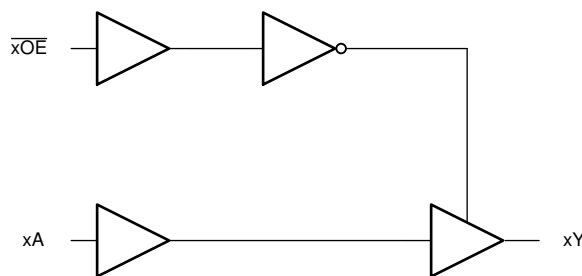
SN74LV4T125-Q1 は、4 つの独立した 3 ステート出力付きバッファを内蔵し、広い電圧範囲で動作してレベル変換を実現します。各バッファはブール関数  $Y = A$  を正論理で実行します。 $\overline{OE}$  ピンに HIGH を印加することで、出力をハイ・インピーダンス (Hi-Z) 状態にできます。出力レベルは電源電圧 ( $V_{CC}$ ) を基準としており、1.8V、2.5V、3.3V、5V の CMOS レベルをサポートしています。

入力は低スレッショルド回路を使用して設計され、低電圧 CMOS 入力の昇圧変換 (例: 1.2V 入力から 1.8V 出力、1.8V 入力から 3.3V 出力) をサポートします。また、5V 許容の入力ピンにより、降圧変換 (例: 3.3V 入力から 2.5V 出力) が可能です。

### 製品情報<sup>(1)</sup>

部品番号	パッケージ	本体サイズ (公称)
SN74LV4T125-Q1	TSSOP (14)	5.00mm × 4.40mm

(1) 利用可能なパッケージについては、このデータシートの末尾にある注文情報を参照してください。



概略論理図 (正論理)



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## 4 Revision History

Changes from Revision * (March 2022) to Revision A (June 2022)	Page
• データシートのステータスを「事前情報」から 量産データに更新 .....	1

## 5 Pin Configuration and Functions

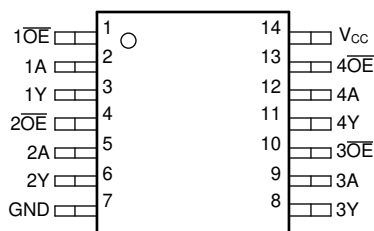


图 5-1. PW Package,  
14-Pin TSSOP  
(Top View)

表 5-1. Pin Functions

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
1OE	1	I	Channel 1, output enable, active low
1A	2	I	Channel 1, input A
1Y	3	O	Channel 1, output Y
2OE	4	I	Channel 2, output enable, active low
2A	5	I	Channel 2, input A
2Y	6	O	Channel 2, output Y
GND	7	G	Ground
3Y	8	I	Channel 3, output Y
3A	9	I	Channel 3, input A
3OE	10	I	Channel 3, output enable, active low
4Y	11	O	Channel 4, output Y
4A	12	I	Channel 4, input A
4OE	13	I	Channel 4, output enable, active low
V <sub>CC</sub>	14	P	Positive supply

(1) I = input, O = output, I/O = input or output, G = ground, P = power.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage range	-0.5	7	V
$V_I$	Input voltage range	-0.5	7	V
$V_O$	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	4.6	V
$V_O$	Voltage range applied to any output in the HIGH or LOW state <sup>(2)</sup>	-0.5	$V_{CC} + 0.5$	V
$I_{IK}$	Input clamp current	$V_I < -0.5$ V	-20	mA
$I_{OK}$	Output clamp current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V	±50	mA
$I_O$	Continuous output current	$V_O = 0$ to $V_{CC}$	±35	mA
	Continuous output current through $V_{CC}$ or GND		±70	mA
$T_{stg}$	Storage temperature	-65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 HBM ESD Classification Level 2 <sup>(1)</sup>	±4000	V
		Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B	±2000	

- (1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

PARAMETER		CONDITION	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.6	5.5	V
V <sub>I</sub>	Input Voltage		0	5.5	V
V <sub>O</sub>	Output Voltage	3-state (Hi-Z)	0	V <sub>CC</sub>	V
		HIGH or LOW state	0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 1.65 V to 2 V	1.1		V
		V <sub>CC</sub> = 2.25 V to 2.75 V	1.28		
		V <sub>CC</sub> = 3 V to 3.6 V	1.45		
		V <sub>CC</sub> = 4.5 V to 5.5 V	2.00		
V <sub>IL</sub>	Low-Level input voltage	V <sub>CC</sub> = 1.65 V to 2 V		0.51	V
		V <sub>CC</sub> = 2.25 V to 2.75 V		0.65	
		V <sub>CC</sub> = 3 V to 3.6 V		0.75	
		V <sub>CC</sub> = 4.5 V to 5.5 V		0.8	
I <sub>O</sub>	Output Current	V <sub>CC</sub> = 1.65 V to 2.0 V		±8	mA
		V <sub>CC</sub> = 2.25 V to 2.75 V		±15	
		V <sub>CC</sub> = 3.3 V to 5.0 V		±25	
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 1.6 V to 5.0 V		20	ns/V
T <sub>A</sub>	Operating free-air temperature		–40	125	°C

- (1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, [Implications of Slow or Floating CMOS Inputs](#).

## 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		SN74LV4T125-Q1	UNIT
		PW (TSSOP)	
		14 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	151.0	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	80.0	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	94.2	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	28.0	°C/W
Y <sub>JB</sub>	Junction-to-board characterization parameter	93.6	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics

over operating free-air temperature range; typical values measured at  $T_A = 25^\circ\text{C}$  (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	TEST CONDITIONS	$V_{CC}$	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{OH}$	$I_{OH} = -50\ \mu\text{A}$	1.65 V to 5.5 V	$V_{CC} - 0.1$			$V_{CC} - 0.1$			V
	$I_{OH} = -2\ \text{mA}$	1.65 V	1.4	1.7 <sup>(1)</sup>		1.35			
	$I_{OH} = -3\ \text{mA}$	2.3 V	2.05	2.4 <sup>(1)</sup>		2			
	$I_{OH} = -5\ \text{mA}$	3 V	2.7	3.08 <sup>(1)</sup>		2.6			
	$I_{OH} = -16\ \text{mA}$	4.5 V	3.7	4.65 <sup>(1)</sup>		3.6			
$V_{OL}$	$I_{OL} = 50\ \mu\text{A}$	1.65 V to 5.5 V			0.1			0.1	V
	$I_{OL} = 2\ \text{mA}$	1.65 V		0.1 <sup>(1)</sup>	0.2			0.3	
	$I_{OL} = 3\ \text{mA}$	2.3 V		0.1 <sup>(1)</sup>	0.2			0.3	
	$I_{OL} = 5\ \text{mA}$	3 V		0.2 <sup>(1)</sup>	0.35			0.4	
	$I_{OL} = 16\ \text{mA}$	4.5 V		0.3 <sup>(1)</sup>	0.55			0.55	
$I_I$	$V_I = 0\ \text{V}$ or $V_{CC}$	0 V to 5.5 V			$\pm 0.1$			$\pm 1$	$\mu\text{A}$
$I_{CC}$	$V_I = 0\ \text{V}$ or $V_{CC}$ , $I_O = 0$ ; open on loading	1.8 V to 5.5 V			2			20	$\mu\text{A}$
$\Delta I_{CC}$	One input at 0.3 V or 3.4 V, other inputs at 0 or $V_{CC}$ , $I_O = 0$	5.5 V			1.35			1.5	mA
	One input at 0.3 V or 1.1 V, other inputs at 0 or $V_{CC}$ , $I_O = 0$	1.8 V			10			10	$\mu\text{A}$
$I_{OZ}$	$V_O = V_{CC}$ or GND	5.5 V			$\pm 0.25$			$\pm 2.5$	$\mu\text{A}$
$I_{OFF}$	$V_O$ or $V_I = 0\ \text{V}$ to 5.5 V	0 V			0.5			5	$\mu\text{A}$
$C_I$	$V_I = V_{CC}$ or GND	3.3 V		1.6		1.6			pF
$C_O$	$V_O = V_{CC}$ or GND	3.3 V		4.8		4.8			pF
$C_{PD}$ <sup>(2) (3)</sup>	$C_L = 50\ \text{pF}$ , $F = 10\ \text{Mhz}$	5 V		16					pF

(1) Typical value at nearest nominal voltage (1.8 V, 2.5 V, 3.3 V, and 5 V)

(2)  $C_{PD}$  is used to determine the dynamic power consumption, per channel.

(3)  $P_D = V_{CC}^2 \times F_I \times (C_{PD} + C_L)$  where  $F_I$  = input frequency,  $C_L$  = output load capacitance,  $V_{CC}$  = supply voltage.

## 6.6 Switching Characteristics 1.8-V $V_{CC}$

over operating free-air temperature range (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
$t_{pd}$	A	Y	$C_L = 15\ \text{pF}$		9.1	13.1			20.2	nS
			$C_L = 50\ \text{pF}$		12.6	17.9			25	
$t_{dis}$	$\overline{OE}$	Y	$C_L = 15\ \text{pF}$		7.6	16.2			23.8	nS
			$C_L = 50\ \text{pF}$		14.5	21			23.8	
$t_{en}$	$\overline{OE}$	Y	$C_L = 15\ \text{pF}$		8.6	15.2			17.9	nS
			$C_L = 50\ \text{pF}$		12.1	18			22.6	
$t_{sk(o)}$			$C_L = 50\ \text{pF}$						1	nS

## 6.7 Switching Characteristics 2.5-V $V_{CC}$

over operating free-air temperature range (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
$t_{pd}$	A	Y	$C_L = 15\text{ pF}$		6.9	9.9			15.3	nS
			$C_L = 50\text{ pF}$		9.6	13.5			19	
$t_{dis}$	$\overline{OE}$	Y	$C_L = 15\text{ pF}$		5.8	12.3			18.1	nS
			$C_L = 50\text{ pF}$		11	15.9			18.1	
$t_{en}$	$\overline{OE}$	Y	$C_L = 15\text{ pF}$		6.5	9.2			13.5	nS
			$C_L = 50\text{ pF}$		9.2	12.8			17.1	
$t_{sk(o)}$			$C_L = 50\text{ pF}$						1	nS

## 6.8 Switching Characteristics 3.3-V $V_{CC}$

over operating free-air temperature range (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
$t_{pd}$	A	Y	$C_L = 15\text{ pF}$		5.5	7.9			12.2	nS
			$C_L = 50\text{ pF}$		7.6	10.8			15.1	
$t_{dis}$	$\overline{OE}$	Y	$C_L = 15\text{ pF}$		4.6	9.8			14.4	nS
			$C_L = 50\text{ pF}$		8.8	12.7			14.4	
$t_{en}$	$\overline{OE}$	Y	$C_L = 15\text{ pF}$		5.2	7.3			10.8	nS
			$C_L = 50\text{ pF}$		7.3	10.2			13.7	
$t_{sk(o)}$			$C_L = 50\text{ pF}$						1	nS

## 6.9 Switching Characteristics 5.0-V $V_{CC}$

over operating free-air temperature range (unless otherwise noted). See *Parameter Measurement Information*.

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
$t_{pd}$	A	Y	$C_L = 15\text{ pF}$		3.8	5.5			8.5	nS
			$C_L = 50\text{ pF}$		5.3	7.5			10.5	
$t_{dis}$	$\overline{OE}$	Y	$C_L = 15\text{ pF}$		3.2	6.8			10	nS
			$C_L = 50\text{ pF}$		6.1	8.8			10	
$t_{en}$	$\overline{OE}$	Y	$C_L = 15\text{ pF}$		3.6	5.1			7.5	nS
			$C_L = 50\text{ pF}$		5.1	7.1			9.5	
$t_{sk(o)}$			$C_L = 50\text{ pF}$						1	nS

## 6.10 Noise Characteristics

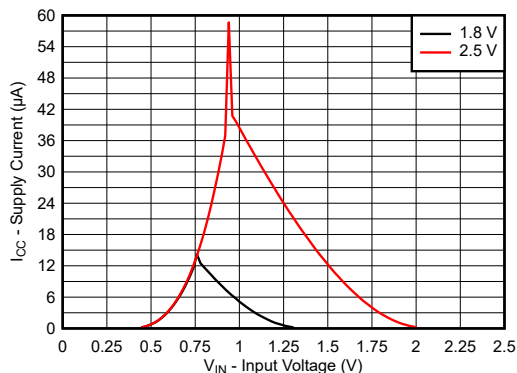
$V_{CC} = 3.3\text{ V}$ ,  $C_L = 50\text{ pF}$ ,  $T_A = 25^\circ\text{C}$  (1)

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic $V_{OL}$		0.4	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic $V_{OL}$		-0.3	-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic $V_{OH}$		3		V
$V_{IH(D)}$	High-level dynamic input voltage	2.31			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

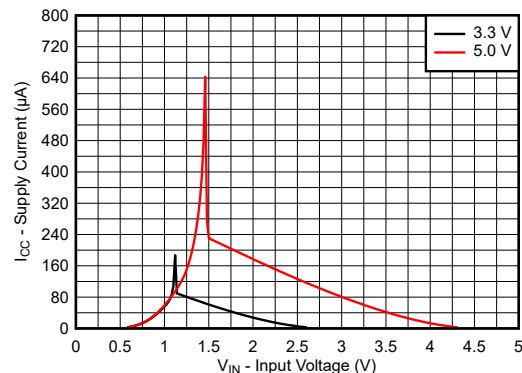
(1) Characteristics are for surface-mount packages only

## 6.11 Typical Characteristics

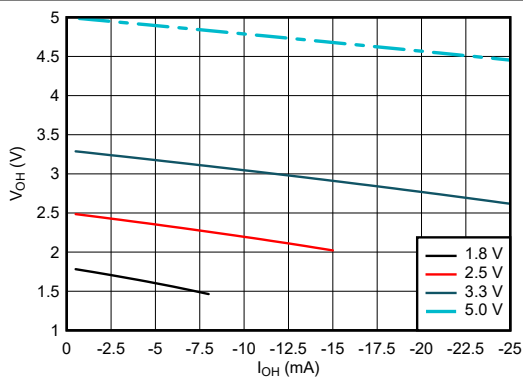
$T_A = 25^\circ\text{C}$  (unless otherwise noted)



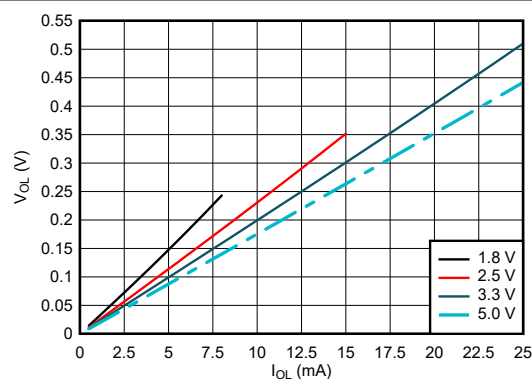
6-1. Supply Current Across Input Voltage 1.8-V and 2.5-V Supply



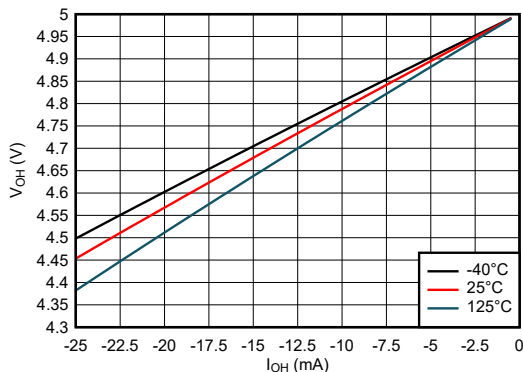
6-2. Supply Current Across Input Voltage 3.3-V and 5.0-V Supply



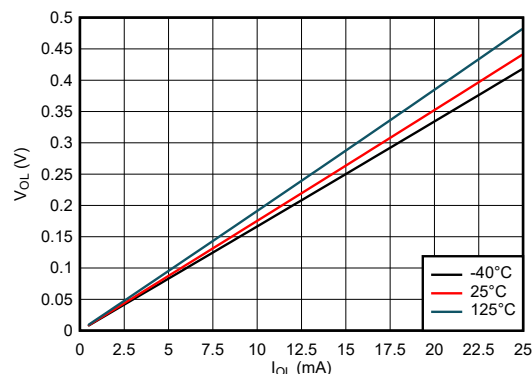
6-3. Output Voltage vs Current in HIGH State



6-4. Output Voltage vs Current in LOW State



6-5. Output Voltage vs Current in HIGH State; 5-V Supply



6-6. Output Voltage vs Current in LOW State; 5-V Supply



## 6.11 Typical Characteristics (continued)

$T_A = 25^\circ\text{C}$  (unless otherwise noted)

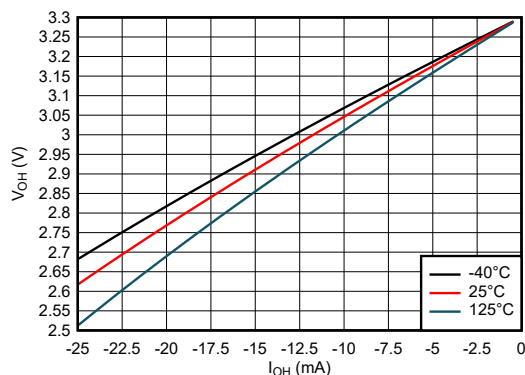


FIG 6-7. Output Voltage vs Current in HIGH State; 3.3-V Supply

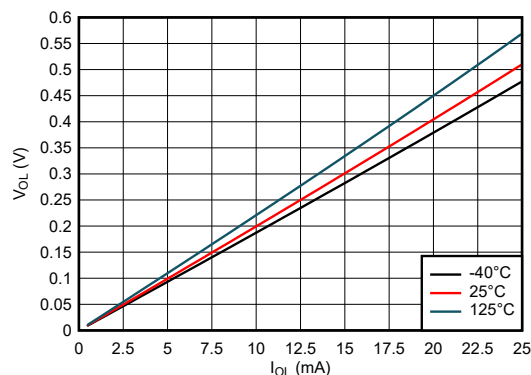


FIG 6-8. Output Voltage vs Current in LOW State; 3.3-V Supply

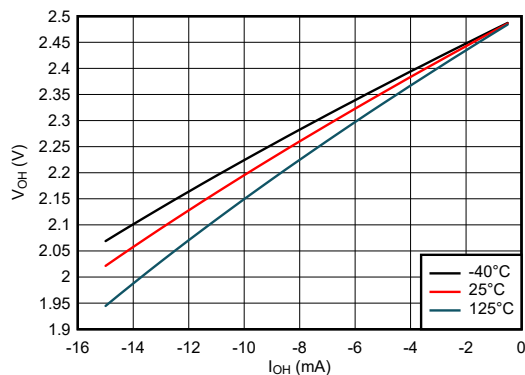


FIG 6-9. Output Voltage vs Current in HIGH State; 2.5-V Supply

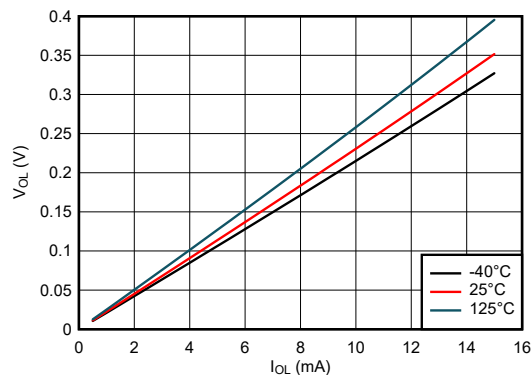


FIG 6-10. Output Voltage vs Current in LOW State; 2.5-V Supply

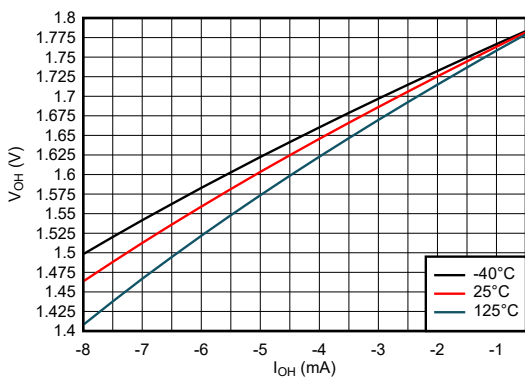


FIG 6-11. Output Voltage vs Current in HIGH State; 1.8-V Supply

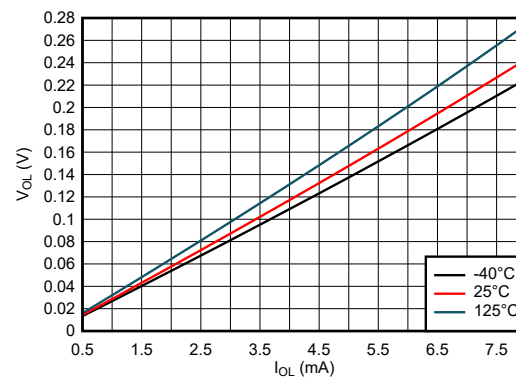


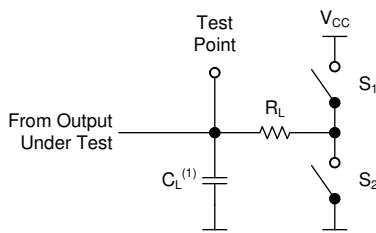
FIG 6-12. Output Voltage vs Current in LOW State; 1.8-V Supply

## 7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics:  $\text{PRR} \leq 1 \text{ MHz}$ ,  $Z_O = 50 \Omega$ .

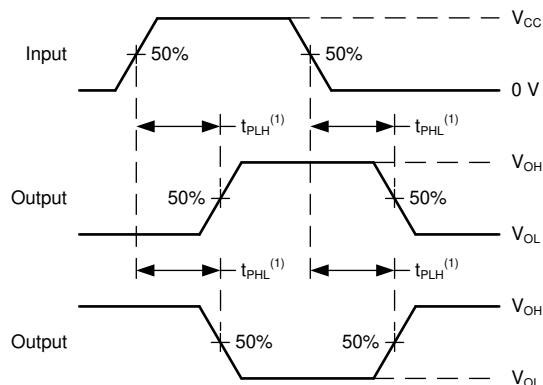
For clock inputs,  $f_{\text{max}}$  is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



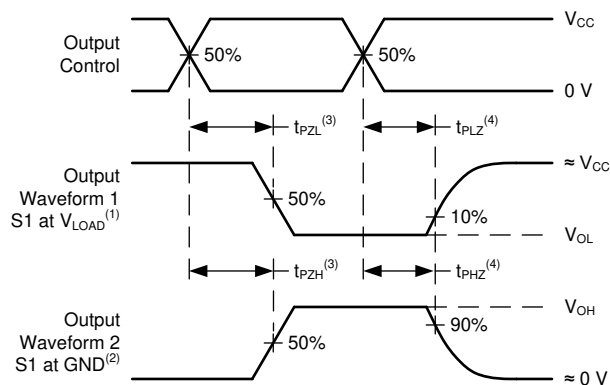
(1)  $C_L$  includes probe and test-fixture capacitance.

**7-1. Load Circuit for 3-State Outputs**



(1) The greater between  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  is the same as  $t_{\text{pd}}$ .

**7-2. Voltage Waveforms Propagation Delays**



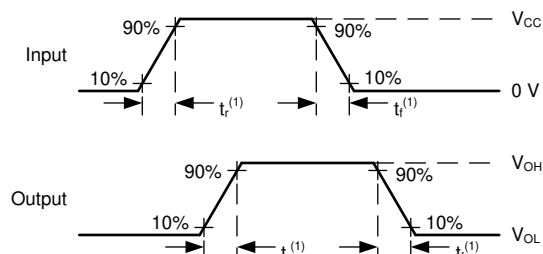
(1) S1 = CLOSED, S2 = OPEN.

(2) S1 = OPEN, S2 = CLOSED.

(3) The greater between  $t_{\text{PZL}}$  and  $t_{\text{PZH}}$  is the same as  $t_{\text{en}}$ .

(4) The greater between  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}$  is the same as  $t_{\text{dis}}$ .

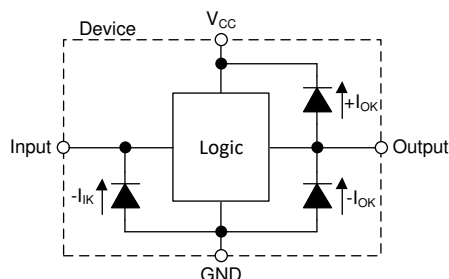
**7-3. Voltage Waveforms Propagation Delays**



(1) The greater between  $t_r$  and  $t_f$  is the same as  $t_t$ .

**7-4. Voltage Waveforms, Input and Output Transition Times**





✎ 8-1. Electrical Placement of Clamping Diodes for Each Input and Output

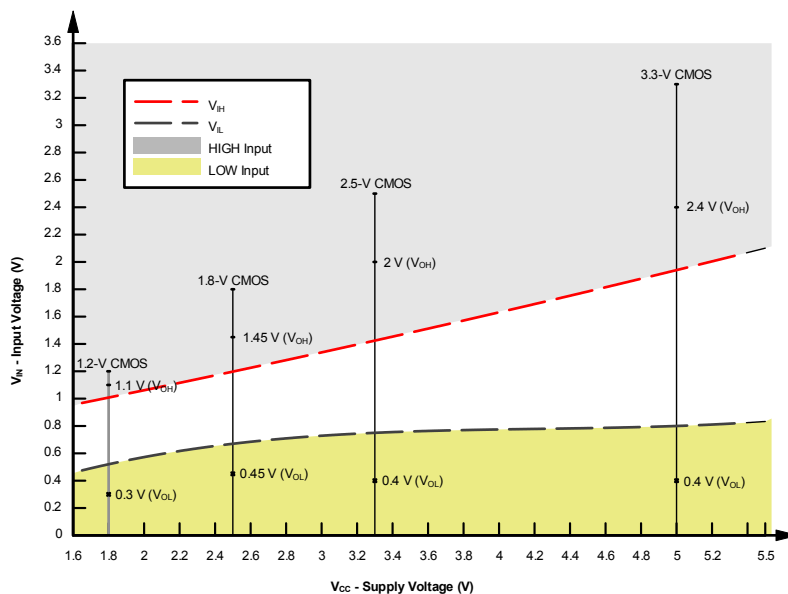
### 8.3.3 LVxT Enhanced Input Voltage

The SN74LV4T125-Q1 belongs to TI's LVxT family of logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5 V levels to support down-translation. The output voltage will always be referenced to the supply voltage ( $V_{CC}$ ), as described in the *Electrical Characteristics* table. To ensure proper functionality, input signals must remain at or below the specified  $V_{IH(MIN)}$  level for a HIGH input state, and at or below the specified  $V_{IL(MAX)}$  for a LOW input state. ✎ 8-2 shows the typical  $V_{IH}$  and  $V_{IL}$  levels for the LVxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law ( $R = V \div I$ ).

The inputs require that input signals transition between valid logic states quickly, as defined by the input transition time or rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in the [Implications of Slow or Floating CMOS Inputs](#) application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at  $V_{CC}$  or GND. If a system will not be actively driving an input at all times, a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; however, a 10-k $\Omega$  resistor is recommended and will typically meet all requirements.



✎ 8-2. LVxT Input Voltage Levels

### 8.3.3.1 Down Translation

Signals can be translated down using the SN74LV4T125-Q1. The voltage applied at the  $V_{CC}$  will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables.

When connected to a high-impedance input, the output voltage will be approximately  $V_{CC}$  in the HIGH state, and 0 V in the LOW state. Ensure that the input signals in the HIGH state are between  $V_{IH(MIN)}$  and 5.5 V, and input signals in the LOW state are lower than  $V_{IL(MAX)}$  as shown in [Figure 8-2](#).

For example, standard CMOS inputs for devices operating at 5.0 V, 3.3 V or 2.5 V can be down-translated to match 1.8 V CMOS signals when operating from 1.8-V  $V_{CC}$ . See [Figure 8-3](#).

*Down Translation Combinations* are as follows:

- 1.8-V  $V_{CC}$  – Inputs from 2.5 V, 3.3 V, and 5.0 V
- 2.5-V  $V_{CC}$  – Inputs from 3.3 V and 5.0 V
- 3.3-V  $V_{CC}$  – Inputs from 5.0 V

### 8.3.3.2 Up Translation

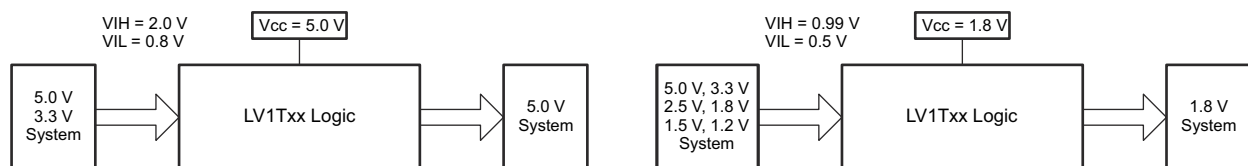
Input signals can be up translated using the SN74LV4T125-Q1. The voltage applied at  $V_{CC}$  will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables. When connected to a high-impedance input, the output voltage will be approximately  $V_{CC}$  in the HIGH state, and 0 V in the LOW state.

The inputs have reduced thresholds that allow for input HIGH state levels which are much lower than standard values. For example, standard CMOS inputs for a device operating at a 5-V supply will have a  $V_{IH(MIN)}$  of 3.5 V. For the SN74LV4T125-Q1,  $V_{IH(MIN)}$  with a 5-V supply is only 2 V, which would allow for up-translation from a typical 2.5-V to 5-V signals.

Ensure that the input signals in the HIGH state are above  $V_{IH(MIN)}$  and input signals in the LOW state are lower than  $V_{IL(MAX)}$  as shown in [Figure 8-3](#).

*Up Translation Combinations* are as follows:

- 1.8-V  $V_{CC}$  – Inputs from 1.2 V
- 2.5-V  $V_{CC}$  – Inputs from 1.8 V
- 3.3-V  $V_{CC}$  – Inputs from 1.8 V and 2.5 V
- 5.0-V  $V_{CC}$  – Inputs from 2.5 V and 3.3 V



**Figure 8-3. LVxT Up and Down Translation Example**

## 8.4 Device Functional Modes

[Function Table](#) lists the functional modes of the SN74LV4T125-Q1.

**Table 8-1. Function Table**

INPUTS <sup>(1)</sup>		OUTPUT
OE	A	Y
L	H	H
L	L	L
H	X	Z

(1) H = high voltage level, L = low voltage level, X = do not care, Z = high impedance

## 9 Application and Implementation

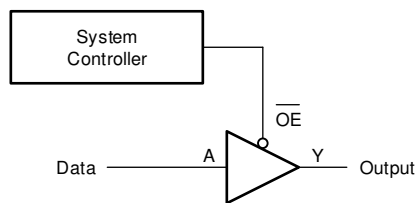
### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 9.1 Application Information

In this application, a buffer with a 3-state output is used to disable a data signal as shown in [Figure 9-1](#). The remaining three buffers can be used for signal conditioning in other places in the system, or the inputs can be grounded and the channels left unused.

### 9.2 Typical Application



**Figure 9-1. Typical Application Block Diagram**

#### 9.2.1 Design Requirements

##### 9.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics* section.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74LV4T125-Q1 plus the maximum static supply current,  $I_{CC}$ , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only source as much current that is provided by the positive supply source. Be sure to not exceed the maximum total current through  $V_{CC}$  listed in the *Absolute Maximum Ratings*.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74LV4T125-Q1 plus the maximum supply current,  $I_{CC}$ , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current that can be sunk into its ground connection. Be sure to not exceed the maximum total current through GND listed in the *Absolute Maximum Ratings*.

The SN74LV4T125-Q1 can drive a load with a total capacitance less than or equal to 50 pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50 pF.

The SN74LV4T125-Q1 can drive a load with total resistance described by  $R_L \geq V_O / I_O$ , with the output voltage and current defined in the *Electrical Characteristics* table with  $V_{OH}$  and  $V_{OL}$ . When outputting in the HIGH state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the  $V_{CC}$  pin.

Total power consumption can be calculated using the information provided in [CMOS Power Consumption and Cpd Calculation](#).

Thermal increase can be calculated using the information provided in [Thermal Characteristics of Standard Linear and Logic \(SLL\) Packages and Devices](#).

### CAUTION

The maximum junction temperature,  $T_{J(max)}$  listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

#### 9.2.1.2 Input Considerations

Input signals must cross  $V_{IL(max)}$  to be considered a logic LOW, and  $V_{IH(min)}$  to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either  $V_{CC}$  or ground. The unused inputs can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input will be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The drive current of the controller, leakage current into the SN74LV4T125-Q1 (as specified in the *Electrical Characteristics*), and the desired input transition rate limits the resistor size. A 10-k $\Omega$  resistor value is often used due to these factors.

The SN74LV4T125-Q1 has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the *Recommended Operating Conditions* table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

#### 9.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the  $V_{OH}$  specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the  $V_{OL}$  specification in the *Electrical Characteristics*.

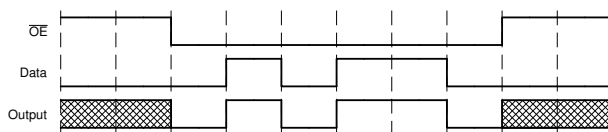
Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to  $V_{CC}$  or ground.

Refer to the *Feature Description* section for additional information regarding the outputs for this device.

#### 9.2.2 Application Curves



**9-2. Application Timing Diagram**

## 10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu\text{F}$  capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1- $\mu\text{F}$  and 1- $\mu\text{F}$  capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

## 11 Layout

### 11.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused (for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used). Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

### 11.2 Layout Example

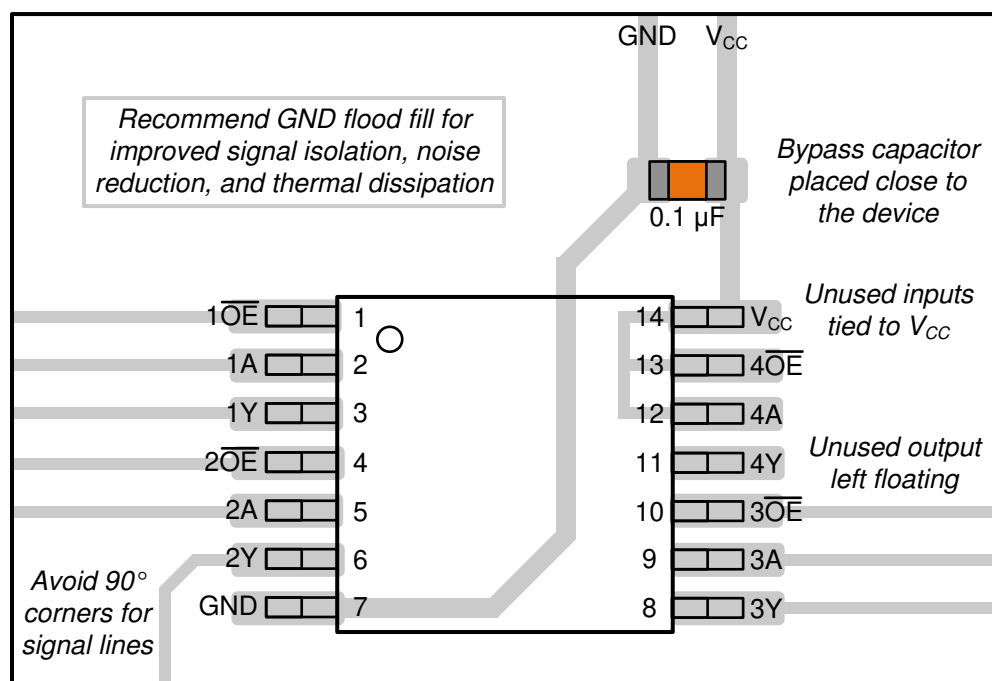


FIG 11-1. Example Layout for the SN74LV4T125-Q1



## 12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [CMOS Power Consumption and  \$C\_{pd}\$  Calculation application report](#)
- Texas Instruments, [Designing With Logic application report](#)
- Texas Instruments, [HCMOS Design Considerations data sheet](#)

### 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.3 サポート・リソース

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### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LV4T125QPWRQ1	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV4125Q
SN74LV4T125QPWRQ1.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV4125Q
SN74LV4T125QPWRQ1.B	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	-	Call TI	Call TI	-40 to 125	

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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### OTHER QUALIFIED VERSIONS OF SN74LV4T125-Q1 :

- Catalog : [SN74LV4T125](#)

- Enhanced Product : [SN74LV4T125-EP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV4T125QPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV4T125QPWRQ1	TSSOP	PW	14	2000	353.0	353.0	32.0



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## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

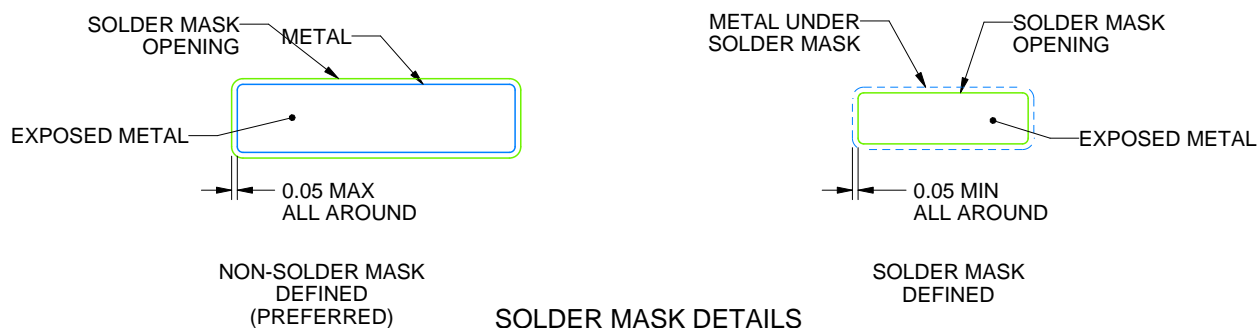
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



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